Silicon NPN Power Transistor





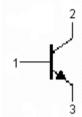
Features:

- High voltage
- · High speed switching

Application:

For use in horizontal deflection circuits of high resolution monitors

Fig. 1 Simplified Outline (TO-3PFa) and Symbol



Pinning

Pin	Description
1	Base
2	Collector
3	Emitter

Absolute Maximum Ratings ($T_a = 25$ °C)

Symbol	Parameter	Conditions	Value	Unit
V _{CBO}	Collector - base voltage	Open emitter	1,500	V
V _{CEO}	Collector - emitter voltage	Open base	700	V
V_{EBO}	Emitter - base voltage	Open collector	7.5	V
I _C	Collector current (DC)	-	8	А
I _{CP}	Collector current (Pulse)	-	15	А
Ι _Β	Base current (DC)	-	4	А
I _{BM}	Base current (Pulse)	-	6	А
P _{tot}	Total power dissipation	T _C = 25°C	34	W
T _j	Junction temperature	-	150	°C
T _{stg}	Storage temperature	-	-65 to 150	°C

Characteristics ($T_j = 25^{\circ}C$ Unless Otherwise Specified)

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V _{CEO (SUS)}	Collector - emitter sustaining voltage	I _C = 100 mA; I _B = 0; L = 25 mH	700	-	-	V
V (BR) EBO	Emitter - base breakdown voltage	I _E = 1 mA; I _C = 0	7.5	13.5	-	V
V _{CEsat}	Collector - emitter saturation voltage	I _C = 4.5 A; I _B = 1.6 A	-	-	1	V

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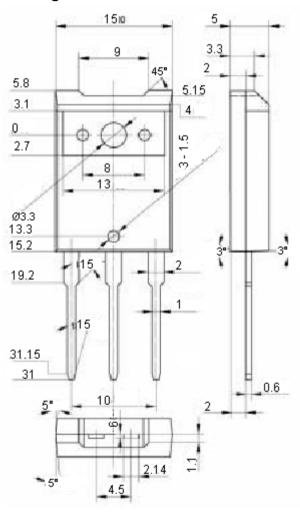
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Characteristics (T_i = 25°C Unless Otherwise Specified)

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V _{BEsat}	Base - emitter saturation voltage	I _C = 4.5 A; I _B = 2 A	-	-	1.1	V
I _{CES}	Collector cut-off current	V_{CE} = Rated V_{CE} ; V_{BE} = 0 T_{C} = 125°C	-	-	1 2	mA
I _{EBO}	Emitter cut-off current	V _{EB} = 6 V; I _C = 0	-	-	10	mA
h _{FE}	DC current gain	I _C = 0.1 A; V _{CE} = 5 V	6	-	30	-
f _T	Transition frequency	I _C = 0.1 A; V _{CE} = 5 V	-	7	-	MHz
C _{OB}	Output capacitance	I _E = 0; V _{CB} = 10 V; f = 1 MHz	-	125	-	pF

Package Outline



Part Number Table

Description	Part Number		
Silicon NPN Power Transistor	BU508AF		

Dimensions: Millimetres

Fig. 2 Outline Dimensions (Unindicated Tolerance: ±0.3 mm)

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